

CMLDM8002A
CMLDM8002AG*
CMLDM8002AJ

SURFACE MOUNT SILICON
DUAL P-CHANNEL
ENHANCEMENT-MODE
MOSFETS



SOT-563 CASE

* Device is *Halogen Free* by design

APPLICATIONS:

- Load/Power Switches
- Power Supply Converter Circuits
- Battery Powered Portable Equipment

MAXIMUM RATINGS: ($T_A=25^\circ\text{C}$)

Drain-Source Voltage	V_{DS}	50	V
Drain-Gate Voltage	V_{DG}	50	V
Gate-Source Voltage	V_{GS}	20	V
Continuous Drain Current	I_D	280	mA
Continuous Source Current (Body Diode)	I_S	280	mA
Maximum Pulsed Drain Current	I_{DM}	1.5	A
Maximum Pulsed Source Current	I_{SM}	1.5	A
Power Dissipation (Note 1)	P_D	350	mW
Power Dissipation (Note 2)	P_D	300	mW
Power Dissipation (Note 3)	P_D	150	mW
Operating and Storage Junction Temperature	T_J, T_{stg}	-65 to +150	$^\circ\text{C}$
Thermal Resistance	Θ_{JA}	357	$^\circ\text{C}/\text{W}$

ELECTRICAL CHARACTERISTICS PER TRANSISTOR: ($T_A=25^\circ\text{C}$ unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS
I_{GSSF}, I_{GSSR}	$V_{GS}=20\text{V}, V_{DS}=0$		100	nA
I_{DSS}	$V_{DS}=50\text{V}, V_{GS}=0$		1.0	μA
I_{DSS}	$V_{DS}=50\text{V}, V_{GS}=0, T_J=125^\circ\text{C}$		500	μA
$I_{D(\text{ON})}$	$V_{GS}=10\text{V}, V_{DS}=10\text{V}$	500		mA
BV_{DSS}	$V_{GS}=0, I_D=10\mu\text{A}$	50		V
$V_{GS(\text{th})}$	$V_{DS}=V_{GS}, I_D=250\mu\text{A}$	1.0	2.5	V
$V_{DS(\text{ON})}$	$V_{GS}=10\text{V}, I_D=500\text{mA}$		1.5	V
$V_{DS(\text{ON})}$	$V_{GS}=5.0\text{V}, I_D=50\text{mA}$		0.15	V
V_{SD}	$V_{GS}=0, I_S=115\text{mA}$		1.3	V

Notes: (1) Ceramic or aluminum core PC Board with copper mounting pad area of 4.0mm²

(2) FR-4 Epoxy PC Board with copper mounting pad area of 4.0mm²

(3) FR-4 Epoxy PC Board with copper mounting pad area of 1.4mm²



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DESCRIPTION:

These CENTRAL SEMICONDUCTOR devices are dual chip P-Channel enhancement-mode MOSFETs, manufactured by the P-Channel DMOS Process, designed for high speed pulsed amplifier and driver applications. The CMLDM8002A utilizes the USA pinout configuration, while the CMLDM8002AJ, utilizing the Japanese pinout configuration, is available as a special order. These special dual transistor devices offer low $r_{DS(\text{on})}$ and low $V_{DS(\text{on})}$.

MARKING CODES: CMLDM8002A: C08

CMLDM8002AG*: CG8

CMLDM8002AJ: CJ8

FEATURES:

- Dual Chip Device
- Low $r_{DS(\text{on})}$
- Low $V_{DS(\text{on})}$
- Low Threshold Voltage
- Fast Switching
- Logic Level Compatible
- Small SOT-563 package

UNITS

V

V

V

mA

mA

mA

mW

mW

mW

$^\circ\text{C}$

$^\circ\text{C}/\text{W}$

**CMLDM8002A
CMLDM8002AG*
CMLDM8002AJ**

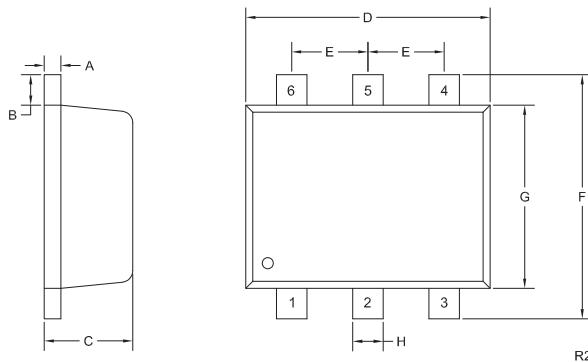
**SURFACE MOUNT SILICON
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ELECTRICAL CHARACTERISTICS PER TRANSISTOR - Continued: ($T_A=25^\circ\text{C}$ unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
$r_{DS(ON)}$	$V_{GS}=10\text{V}, I_D=500\text{mA}$			2.5	Ω
$r_{DS(ON)}$	$V_{GS}=10\text{V}, I_D=500\text{mA}, T_J=125^\circ\text{C}$			4.0	Ω
$r_{DS(ON)}$	$V_{GS}=5.0\text{V}, I_D=50\text{mA}$			3.0	Ω
$r_{DS(ON)}$	$V_{GS}=5.0\text{V}, I_D=50\text{mA}, T_J=125^\circ\text{C}$			5.0	Ω
g_{FS}	$V_{DS}=10\text{V}, I_D=200\text{mA}$	200			mS
C_{rss}	$V_{DS}=25\text{V}, V_{GS}=0, f=1.0\text{MHz}$			7.0	pF
C_{iss}	$V_{DS}=25\text{V}, V_{GS}=0, f=1.0\text{MHz}$			70	pF
C_{oss}	$V_{DS}=25\text{V}, V_{GS}=0, f=1.0\text{MHz}$			15	pF
$Q_g(\text{tot})$	$V_{DS}=25\text{V}, V_{GS}=4.5\text{V}, I_D=100\text{mA}$	0.72			nC
Q_{gs}	$V_{DS}=25\text{V}, V_{GS}=4.5\text{V}, I_D=100\text{mA}$	0.25			nC
Q_{gd}	$V_{DS}=25\text{V}, V_{GS}=4.5\text{V}, I_D=100\text{mA}$	0.16			nC
t_{on}, t_{off}	$V_{DD}=30\text{V}, V_{GS}=10\text{V}, I_D=200\text{mA}$		20		ns
	$R_G=25\Omega, R_L=150\Omega$				

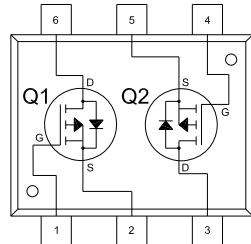
SOT-563 CASE - MECHANICAL OUTLINE



SYMBOL	DIMENSIONS		INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX	MIN	MAX
A	0.0027	0.007	0.07	0.18		
B		0.008		0.20		
C	0.017	0.024	0.45	0.60		
D	0.059	0.067	1.50	1.70		
E		0.020		0.50		
F	0.059	0.067	1.50	1.70		
G	0.043	0.051	1.10	1.30		
H	0.006	0.012	0.15	0.30		

SOT-563 (REV: R2)

**CMLDM8002A (USA Pinout)
CMLDM8002AG***

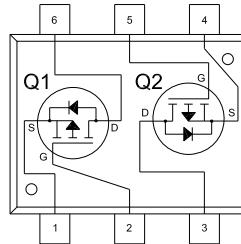


- LEAD CODE:**
- 1) Gate Q1
 - 2) Source Q1
 - 3) Drain Q2
 - 4) Gate Q2
 - 5) Source Q2
 - 6) Drain Q1

MARKING CODES:
CMLDM8002A: C08
CMLDM8002AG*: CG8

* Device is *Halogen Free* by design

CMLDM8002AJ (Japanese Pinout)



- LEAD CODE:**
- 1) Source Q1
 - 2) Gate Q1
 - 3) Drain Q2
 - 4) Source Q2
 - 5) Gate Q2
 - 6) Drain Q1

MARKING CODE: CJ8

R7 (8-June 2015)

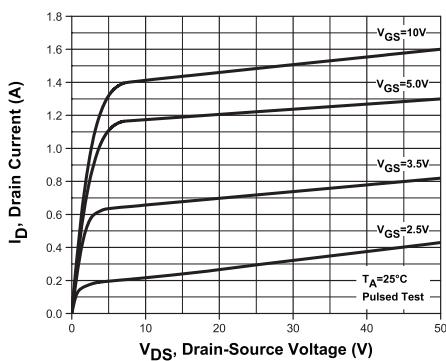
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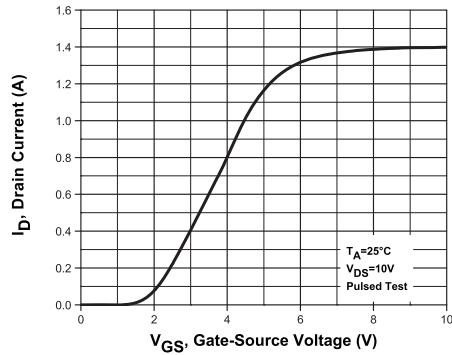


TYPICAL ELECTRICAL CHARACTERISTICS

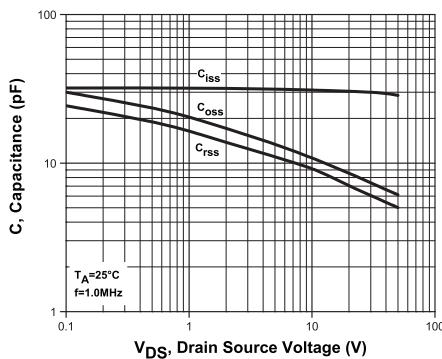
Output Characteristics



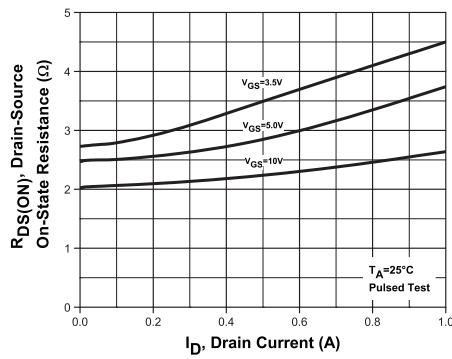
Transfer Characteristics



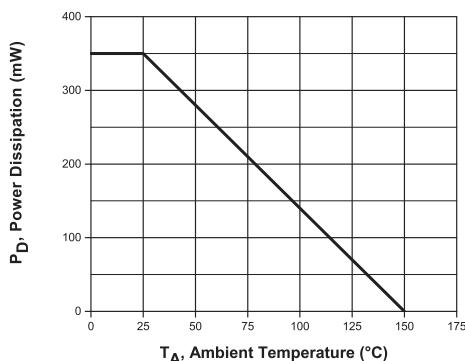
Capacitance



Drain Source On Resistance



Power Derating



R7 (8-June 2015)

OUTSTANDING SUPPORT AND SUPERIOR SERVICES



PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- Inventory bonding
- Consolidated shipping options
- Custom bar coding for shipments
- Custom product packing

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free quick ship samples (2nd day air)
- Online technical data and parametric search
- SPICE models
- Custom electrical curves
- Environmental regulation compliance
- Customer specific screening
- Up-screening capabilities
- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- Application and design sample kits
- Custom product and package development

REQUESTING PRODUCT PLATING

1. If requesting Tin/Lead plated devices, add the suffix " TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
2. If requesting Lead (Pb) Free plated devices, add the suffix " PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

CONTACT US

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